

Multiplexing Superconducting Qubit Circuit for Single Microwave Photon Generation

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Abstract We report on a device that integrates eight superconducting transmon qubits in $\lambda/4$ superconducting coplanar waveguide resonators fed from a common feedline. Using this multiplexing architecture, each resonator and qubit can be addressed individually, thus reducing the required hardware resources and allowing their individual characterisation by spectroscopic methods. The measured device parameters agree with the designed values, and the resonators and qubits exhibit excellent coherence properties and strong coupling, with the qubit relaxation rate dominated by the Purcell effect when brought in resonance with the resonator. Our analysis shows that the circuit is suitable for generation of single microwave photons on demand with an efficiency exceeding 80%.

 $\textbf{Keywords} \ \ \text{Superconducting qubit} \cdot \text{Transmon} \cdot \text{Superconducting resonator} \cdot \text{Single} \\ \text{photon generation}$

1 Introduction

A new paradigm of information processing based on the laws of quantum physics has triggered intensive research into studying physical systems that can be used as the building blocks of a future quantum processor. Remarkable progress towards realising

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quantum information processing elements has been achieved by using both natural and artificial atoms as qubits, and in arranging them into more complex circuits [1]. Artificial atoms are engineered quantum systems that have a number of advantages in comparison with their natural counterparts. First, they are fabricated using existing well-developed nanofabrication methods of conventional electronics and therefore can be placed at will whilst having controllable custom-designed features. Second, their size is macroscopic ($\gtrsim 1\,\mu\text{m}$), which simplifies the task of coupling multiple qubits together into integrated quantum circuits. The large size of artificial atoms results in their large dipole moment which enables strong coupling of individual qubits to electromagnetic field. Third, their energy levels are tunable by external fields, which simplifies control of the quantum states and inter-qubit couplings. As a downside, the undesired coupling to the environment is strong, leading to shorter coherence times of artificial as compared to natural atoms. This requires careful design of the experimental apparatus to protect fragile quantum states.

Superconducting quantum devices containing Josephson junctions can behave like atoms and are primary candidates to being the building blocks of the quantum processor [2]. Whilst there has been enormous progress in the field in the past 15 years or so [3], the superconducting qubit circuits require further optimisation in order to meet the stringent requirements on coherence for large-scale quantum information processing [4]. Nonetheless, the presently available circuits are already good enough for doing quantum optics and atomic physics experiments on a chip [5,6]. A key approach to this is coupling a superconducting qubit to a microwave resonator, thus forming a circuit quantum electrodynamics (cQED) architecture [7,8], which is a solid-state analogue of the cavity QED approach [9] used to study the interaction of natural atoms with photons. In circuit QED, the field confinement produced by the very small mode volume in combination with the macroscopic size of the qubit results in strong qubit—photon coupling, where quantum excitations can transfer between the artificial atom and the resonator and back many times before decay processes become appreciable.

Circuit QED architecture is uniquely suitable for manipulating microwave radiation at the single photon level [8] and for generation of single microwave photons on demand [10,11]. An alternative approach to the single microwave photon generation is based on an artificial superconducting atom directly coupled to an open-end transmission line, a 1D analogue of the 3D half-space [12]. Here we report on a design comprising eight resonators, each housing a superconducting transmon qubit [13] that exhibits good coherence properties. The design allows for efficient frequency multiplexed testing and assessment of the superconducting qubits and is suitable for single microwave photon generation. This involves time-domain control of the quantum state in the superconducting circuit, which is a well-developed technique commonly used in qubit experiments. The key feature of our design is that it allows for multiplexed generation of single photons with an efficiency of >80% using quantum state manipulation and dynamic tuning of the circuit parameters. This provides the means of coupling solid-state qubits with each other for long-distance communications as well as linking stationary and flying qubits.



2 λ/4 Resonator Design

The resonators are designed as coplanar waveguides in superconducting niobium metal film, having a centreline width $W=20\,\mu\mathrm{m}$ and centreline to groundplane spacing of $S=10\,\mu\mathrm{m}$, achieving a characteristic impedance $Z_0\simeq 50\,\Omega$ on our sapphire substrate. We calculate from the geometry of our transmission lines a capacitance per unit length of $c_r\simeq 153~\mathrm{pF/m}$, an inductance per unit length $l_r\simeq 402~\mathrm{nH/m}$, and a phase velocity of $\beta=53.3~\mathrm{radians/m/GHz}$ so that a $\lambda/4~\mathrm{resonator}$ at 7 GHz has a length of 4220 $\mu\mathrm{m}$. The eight $\lambda/4~\mathrm{resonators}$ are designed with unloaded operating frequencies of 7.0, 7.1, 7.2 7.7 GHz by varying the length of a reference design (see Fig. 1a). The resonators are inductively coupled to a common feedline running diagonally across the chip (see Fig. 1b). The coupling strength between the feedline and the resonators is adjusted by a short, $\delta x \sim 400~\mu\mathrm{m}$, section of the resonator parallel to the feedline with centre to centre distance of $44~\mu\mathrm{m}$.

The inductive coupling between the feedline and resonator directly determines the coupling quality factor Q_c of the $\lambda/4$ resonator at the resonator's operating frequency f_0 . Following Barends et al. [14], we have that:

$$Q_{\rm c} = \frac{\pi}{2|S_{21}(f_0)|^2}. (1)$$

We designed for $Q_c = 5000$, corresponding to an $S_{21}(f_0)$ parameter between the feedline and resonator of -35 dB, and a resonance linewidth of $\kappa/2\pi = 1.4$ MHz. Our design is similar to other frequency multiplexed qubit devices [15,16]

3 Qubit Design

All the qubits utilised in the experiment are transmons that are anharmonic LC oscillators whose nonlinear inductance is provided by Josephson junctions. The transmon is essentially a charge qubit [17] whose Josephson junction is shunted by a large capacitor that dominates the total capacitance of the device and thus reduces the sensitivity to charge noise [13]. The qubit is described by the following Hamiltonian:

$$H = 4E_{\rm C}(\hat{n} - n_g)^2 - E_{\rm J}\cos\hat{\phi},\tag{2}$$

where $E_{\rm C}$ and $E_{\rm J}$ are the charging and Josephson energies, respectively; \hat{n} is the number of Cooper pairs transferred between the superconducting electrodes; n_g is the effective offset charge, and $\hat{\phi}$ is the superconducting phase difference between the two electrodes comprising the qubit. The transmon energy level structure is determined entirely by $E_{\rm J}$ and $E_{\rm C}$, and it is operated in the regime $E_{\rm J}\gg E_{\rm C}$. We designed the qubit to have a maximum $|0\rangle \rightarrow |1\rangle$ transition frequency of $\nu_{01}=8.5$ GHz, higher than the bare frequencies of the resonator array, by assuming that $h\nu_{01}=\sqrt{8E_{\rm J}E_{\rm C}}-E_{\rm C}$. For fixed ν_{01} , the ratio $r=E_{\rm J}/E_{\rm C}$ influences the qubit dephasing rate through the sensitivity of ν_{01} to the gate offset charge n_g , with large values of r promoting long relaxation times. At the same time, the value of r determines the maximum qubit



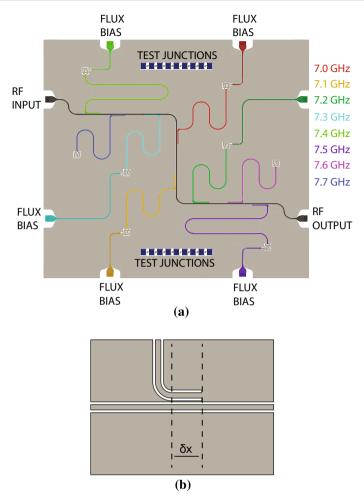


Fig. 1 Device layout and realisation of the eight resonator chip. **a** Schematic layout of the chip showing eight resonators coupled to a common feedline, labelled by unloaded resonant frequencies. Arrays of test junctions are present on the chip to allow for measuring R_N at room temperature. **b** Inductive coupling section optimised to set external Q factor of resonators (Color figure online)

operation speed through the level anharmonicity $|\nu_{01} - \nu_{12}|$, with faster operation times favouring smaller values of r < 100 [13]. Since in our case the qubit forms part of a single photon source where both parameters are important, we selected a compromise value as r = 35 which allows for operation times of the order of tens of ns whilst maintaining long relaxation times (>1 μ s).

The Josephson energy $E_{\rm J}$ and charging energy $E_{\rm C}$ are determined by the device tunnel junction resistance $R_{\rm N}$ and device self-capacitance C_{Σ} , respectively, properties that are under engineering control during fabrication according to the simple relations:

$$R_{\rm N} = \frac{R_{\rm Q}}{2} \frac{\sqrt{8r} - 1}{r} \frac{\nu_{\Delta}}{\nu_{01}} \tag{3}$$

$$C_{\Sigma} = \frac{1}{R_{\rm O}} \frac{\sqrt{8r} - 1}{8} \frac{1}{\nu_{01}},\tag{4}$$

where the quantum resistance $R_Q = h/4e^2 \simeq 6.46 \,\mathrm{k}\,\Omega$ and $v_\Delta = 48.3 \,\mathrm{GHz}$ is related to the superconducting gap Δ in aluminium used to fabricate the tunnel junctions according to $\Delta = hv_\Delta \simeq 200 \,\mu\mathrm{eV}$. Substituting r = 35 and $v_{01} = 8.50 \,\mathrm{GHz}$ yields $R_N = 8.24 \,\mathrm{k}\,\Omega$ and $C_\Sigma = 35.8 \,\mathrm{fF}$, corresponding to a Josephson energy $E_J = 78.2 \,\mu\mathrm{eV}$ and charging energy $E_C = 2.23 \,\mu\mathrm{eV}$. It is also useful to express the charging energy E_C as a frequency v_C following $E_C = hv_C$, and we find $v_C = 540 \,\mathrm{MHz}$.

The final important property of the qubit for our purposes is the state-dependent dispersive shift $\chi/2\pi$ of the resonator [18]. When the qubit and resonator are well detuned from one another, the state of the qubit $|0\rangle$ or $|1\rangle$ 'pulls' the resonator frequency by $\pm \chi/2\pi$, providing a means to read out the qubit state [19].

An analytic expression for $\chi/2\pi$ is known in the Cooper pair box limit where $E_{\rm C} \sim E_{\rm J}$, but is strictly inapplicable for our transmon devices due to the influence of the higher excited states and the near degeneracy of the $|0\rangle \rightarrow |1\rangle$ and $|1\rangle \rightarrow 2$ transitions. [20,21]. We use the expression, nevertheless, to provide an estimate of the gate capacitance required to realise an acceptable dispersive shift. We find:

$$\frac{C_g}{C_{\Sigma}} = \left(\frac{2}{r}\right)^{1/4} \left(\frac{\Delta_0}{\nu_{\rm rms}^0}\right) \left(\frac{\chi}{2\pi\nu_C}\right)^{1/2} \left(1 - \frac{\nu_C}{\Delta_0}\right)^{1/2},\tag{5}$$

where $\Delta_0 = 8.5 - 7 = 1.5$ GHz is the qubit–resonator detuning, v_C is the charging energy expressed as a frequency (540 MHz), and $hv_{\rm rms}^0 = eV_{\rm rms}^0$ describes the vacuum RMS voltage fluctuations of the resonator. We have that:

$$v_{\rm rms}^0 = \frac{eV_{\rm rms}^0}{h} = \left(\frac{1}{2} \frac{v_r}{R_{\rm Q} \lambda c_r}\right)^{\frac{1}{2}},$$
 (6)

where λ is the wavelength of the resonator, and c_r is the capacitance per unit length of the coplanar waveguide, so that in our $\lambda/4$ resonators, $V_{\rm rms}^0 = 2.58 \,\mu{\rm V}$ and $v_{\rm rms}^0 = 623 \,{\rm MHz}$. Substituting the values above determines the desired coupling capacitance as $C_g = 0.09 C_{\Sigma}$

The self-capacitance C_{Σ} of the device is the sum of the tunnel junction capacitance and the geometric capacitance. We estimate the junction capacitance using a typical value of the specific capacitance for Al ultrasmall tunnel junctions of 45 fF/ μ m² [22], which for our junction area of $100 \times 100 \, \mathrm{nm^2}$ gives $\simeq 0.45 \, \mathrm{fF}$. Clearly, the junction capacitance contributes only about 1% to C_{Σ} and we can safely neglect it. This in turn yields $C_g = 3.2 \, \mathrm{fF}$.

The qubit self-capacitance C_{Σ} is then realised through adjusting the shunt geometry, whilst the qubit gate capacitance is realised by adjusting the separation between the end of the transmission line and the qubit shunt. The device geometry was designed using the COMSOL electromagnetics modelling package to obtain the desired C_{Σ} and C_g . To obtain the desired R_N and thus E_J , the junction oxidation time and pressure were adjusted to obtain a tunnel resistance of $8.2\,\mathrm{k}\Omega$ measured through the parallel



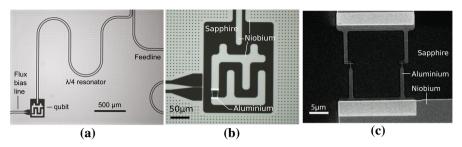


Fig. 2 a A $\lambda/4$ resonator inductively coupled to a feedline and capacitively coupled to a transmon qubit **b** Close-up of the transmon qubit **c** Scanning electron microscope image of the SQUID loop tunnel junction

combination of the two nominally $100 \times 100 \text{ nm}^2$ tunnel junctions in the device SQUID loop. The junction resistance was confirmed by measuring test junctions of the same dimensions as the transmon device, fabricated on the same chip, as shown in Fig. 2c.

4 Device Fabrication

The samples were fabricated on a single-crystal c-axis oriented sapphire wafer. The fabrication process involved two major steps: patterning of the niobium groundplane, followed by deposition of the transmon structure and tunnel junctions. Both stages of the device fabrication utilised electron beam lithography at 100 kV.

1. Patterning of the groundplane The feedline, $\lambda/4$ resonators and qubit shunt capacitors were formed by etching a 100 nm niobium metal film deposited by DC magnetron sputtering onto the sapphire wafer. The metal-coated wafer was spin-coated with AR6200(EL11) resist at 6000 rpm for 60 s, and the resist was baked on a hotplate at 150°C for 9 min before the resonator and feedline structures were exposed in an e-beam writer to a dose of $350\,\mu\text{C/cm}^2$ using a 58 nA beam current and proximity correction routine. The exposed wafer was developed in AR600-546 developer for 3 min before immersing in isopropyl alcohol to halt the development process. The resulting wafer was dried using N₂ gas, and the resist was reflow baked for 5 min at 150°C . An SF₆+O₂ reactive ion etching process was then used to transfer the pattern from the resist into the niobium film. The reactive ion etching chamber was preconditioned for 10 min before the samples were loaded and etched for 3 min 15 s, resulting in pattern transfer into the niobium film. The e-beam resist was removed by immersing in AR600-71 solvent for 5 min, followed by sonicating in acetone for 1 min and rinsing in isopropyl alcohol for 1 min, before drying in N₂ gas.

The patterned wafer was then coated with a protective layer of AZ5214E photoresist before dicing into $8\times8\,\mathrm{mm}$ chips using a hubless resin blade. Following dicing, the protective resist was removed in acetone followed by isopropyl alcohol and N_2 drying.

2. Deposition of transmon tunnel junctions The chips were prepared for qubit junction deposition by spin-coating with two layers of MMA(8.5)MAA EL11 resist, at 4000 rpm for 60 s, and then baking each layer for 2 min at 160°C, to create a 1 μ m film of MMA(8.5)MAA resist, followed by a single layer of 950 PMMA A4 spun at 4000 rpm for 60 s and baked for 10 min at 160°C to produce a 200 nm film. To avoid



excessive charging during e-beam exposure, the resist structure was coated with an "E-spacer 300z" conductive layer by spinning at 4000 rpm for 60 s. The qubit patterns were exposed using a beam current of $1.1\,\mathrm{nA}$ on fine structures and $10\,\mathrm{nA}$ on coarse structures. The exposed resist was developed by rinsing in flowing deionised water for 30 s to remove the E-spacer layer, followed by immersion in 1:4 vol/vol methyl isobutyl ketone/isopropyl alcohol developer for 20 s, and then immersion in a 1:2 vol/vol mixture of methyl glycol/methanol for 20 s, followed by immersion in isopropyl alcohol for 10 s to halt development, before blowing dry with N_2 gas.

The resulting resist structure was used to deposit the qubit junctions in an electron beam evaporation chamber equipped with a tilting sample stage, argon ion milling capability and O_2 inlet needle valve. The sample surface was first cleaned by ion milling for 5 min using 1 kV argon ions with a nominal ion beam current density of $100\,\mu\text{A/cm}^2$. The sample position under the ion beam was adjusted so as to clean the sample surface whilst preserving the resist mask. A 20 nm aluminium film was evaporated whilst the stage was tilted at -17° . The aluminium was then oxidised in 4 mbar O_2 for 4 min before a second 20 nm aluminium layer was deposited with the stage tilted to $+17^\circ$. The resulting chips were subjected to a lift-off process in warm acetone at 52° for 30 minutes, followed by a cleaning rinse in fresh acetone, isopropanol and drying with N_2 gas. The normal state resistance of the parallel combination of two nominally $100 \times 100 \, \text{nm}^2$ tunnel junctions was measured and found to be $8.2 \, \text{k}\Omega$.

5 Device Characterisation

5.1 Measurement Setup and Resonator Characterisation

The chip containing superconducting elements was bonded to a printed circuit board and mounted at the mixing chamber plate in a cryogen-free dilution refrigerator with a base temperature around $10 \,\mathrm{mK}$. The sample houses eight resonators and eight qubits to provide redundancy against fabrication yield issues related to individual resonators or qubits and to provide a choice of frequency of the emitted microwave photon. The feedline was bonded to the input and output coaxial lines as shown in Fig. 3. The microwave signal from the room temperature source was attenuated at different temperatures inside the cryostat to suppress the black-body radiation that would otherwise reach the sample. On the output side, the chip was protected from the amplifier input noise and black-body radiation by two isolators mounted at the base temperature. The outgoing signal was amplified by 39 dB at 3 K before it was amplified further by 40 dB at room temperature. The qubit level spacing was controlled through the adjustment of $E_{\rm J}$ by an external magnetic field threading the qubit SQUID loop, which was generated both by a small superconducting coil placed under the chip holder and by on-chip flux bias lines capable of producing a magnetic field local to each qubit.

Initial characterisation of the sample was performed by measuring the feedline transmission S_{21} around 6.8–7.8 GHz, which identified the $\lambda/4$ resonators. We chose to focus the study on the resonator at 7.5 GHz. The transmission past this resonator at an incident power in the single photon regime is shown in Fig. 4a and corresponds to an external quality factor $Q_c \simeq 5500$, or a resonator decay rate $\kappa/2\pi \simeq 1.4$ MHz. The



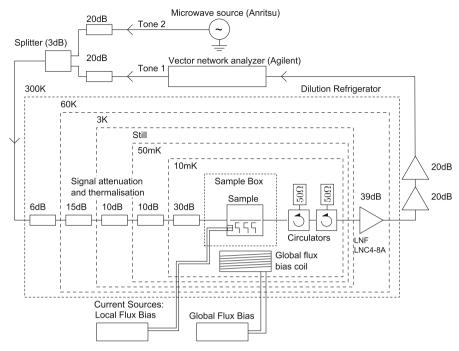


Fig. 3 A schematic of the measurement setup, showing the flux biasing circuitry, microwave measurement circuitry, and microwave attenuation at each stage of the dilution refrigerator

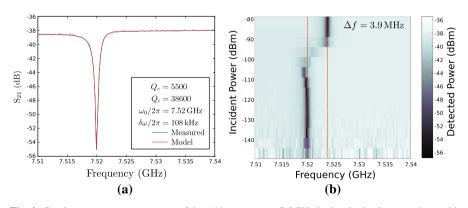


Fig. 4 Continuous wave spectroscopy of the $\lambda/4$ resonator at 7.5 GHz in the single photon regime, with the qubit tuned to the 'sweet spot' of $\nu_{01}=8.501$ GHz. a Transmission past the resonator at 7.52 GHz and b resonance frequency as a function of probe power, showing the shift between the dressed $|0\rangle$ state of the qubit+resonator system (at powers below $-110\,\mathrm{dBm}$) and the bare resonator frequency (at powers above $-90\,\mathrm{dBm}$) for a qubit-resonator detuning of $990\,\mathrm{MHz}$ (Color figure online)

resonance lineshape is well fit using the method of [23] by assuming the resonator is overcoupled to the feedline, with an internal quality factor of at least $Q_i \gtrsim 38600$. The true internal quality factor is difficult to measure in our device due to the deliberate



overcoupling of the resonators, however values in the literature can be optimised to yield $Q_i \gtrsim 1 \times 10^6$ [24].

5.2 Dispersive Shift Measurement

The presence of the qubit was confirmed by the dispersive shift of the resonator frequency due to the interaction of the resonator and the nonlinear element, which was measured by single-tone spectroscopy, sweeping the frequency and power of a probe tone in a continuous wave experiment, whilst measuring transmission through the feedline with a vector network analyser. As shown in Fig. 4b, at input powers below $-110\,\mathrm{dBm}$ the qubit is in the dressed ground state $|0\rangle$ and experiences a shift towards lower frequencies. At input powers above $\geq -90\,\mathrm{dBm}$, the resonator becomes populated with many photons and the resonance frequency returns to that of the bare resonator [21,25,26]. With the qubit–resonator detuning $\Delta_0 = 990\,\mathrm{MHz}$, we observed a shift between the dressed ground state $|0\rangle$ and the bare resonator of 3.9 MHz.

5.3 Qubit-Resonator Coupling: 'g' Measurement

Once the presence of the qubit was confirmed, the hybridisation between the resonator and qubit states was investigated by flux tuning the Josephson energy E_J and hence the resonator–qubit detuning Δ_0 . The effective Josephson energy of our device follows:

$$E_{\rm J} = E_{\rm J}^{\rm max} \left| \cos \left(\frac{\pi \, \Phi}{\Phi_0} \right) \right| \tag{7}$$

where Φ is the magnetic flux through the SQUID loop, $\Phi_0 = h/2e$ is the flux quantum, and E_J^{max} is the Josephson energy at $\Phi = 0$. To achieve flux tuning of the device, we use both a small solenoid external to the sample and an on-chip flux bias line to manipulate the Josephson energy. We use a two-tone spectroscopy technique to investigate the coupled qubit–resonator system [18], measuring transmission past the resonator whilst sending a probe tone to excite the qubit. Through use of this method, we are able to trace out the qubit and resonator frequencies as a function of the applied magnetic flux Φ , presented in Fig. 5, showing the anti-crossing of the qubit and resonator states at around $\Phi = 0.23 \, \Phi_0$. The data are well fit by assuming a resonator qubit coupling of $g/2\pi = 54.3 \, \text{MHz}$. Also visible in Fig. 5b are faint features arising from a qubit located in another resonator hybridising with the resonator under study. These result from our method of applying a magnetic flux globally to the whole chip.

5.4 Qubit Characterisation

5.4.1 Rabi Oscillations

To characterise the qubit, we measured coherent Rabi oscillations around the qubit maximal gap where the energy bands are first order insensitive to the magnetic field



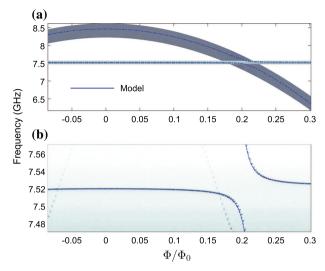


Fig. 5 textbfa Measured transition frequencies of resonator and qubit states determined by monitoring the resonator dispersive shift, as a function of applied flux bias Φ . b Close-up of the resonator-qubit hybridisation point, showing the anti-crossing of the resonator and qubit states. (Model of the hybridised resonator-qubit states shown overlaid.) The *faint diagonal lines* visible are due to weak hybridisation of the resonator under study with a qubit in a remote resonator (Color figure online)

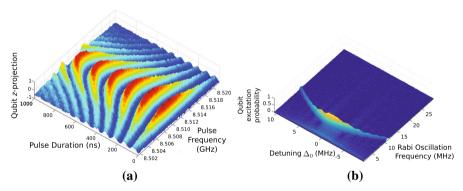


Fig. 6 a Rabi oscillations recorded as a function of pulse frequency and pulse duration. b Fourier transform of Rabi oscillation plot against pulse (Color figure online)

(the "sweet spot"), by sweeping a variable length pulse from 8.502 to 8.520 GHz, with durations from 0 to 1000 ns. We inferred the qubit state by measuring the dispersive shift of the resonator through $\pm \chi/2\pi$ [18]. The Rabi oscillations are presented in Fig. 6a and Fourier transformed in Fig. 6b. The oscillations exhibit a typical pattern [27], with the lowest oscillation frequency, $\Omega=6.17\,\mathrm{MHz}$, at the drive frequency of 8.512 GHz when the drive frequency matches the qubit gap. At zero detuning, the probability for the qubit to be in the excited state is close to unity. When the drive frequency is detuned by Δ_0 to lower or higher frequency from the qubit sweet spot, the Rabi oscillation frequency increases as $\sqrt{\Omega^2+\Delta_0^2}$. Also, as expected, when the



drive frequency is detuned from the sweet spot, the probability of the excited state decreases as $\Omega^2/(\Omega^2+\Delta_0^2)$ and also the qubit decoheres faster. From these data, we found that for our microwave amplitude at zero detuning, it takes about 80 ns to transfer the qubit from the ground to excited state. For comparison, an optimised state of the art system can accomplish the excitation in ~ 1 ns [28]. The pulse that performs this excitation is called the π -pulse.

5.4.2 T₁ and T₂ Measurements

To characterise the coherence properties of the transmon qubit, we measured the qubit energy relaxation time T_1 by exciting the qubit from the ground to first excited state using a π pulse at the qubit frequency ω_a , before measuring the resonator transmission at the frequency $\omega_r = 2\pi f_0$, then varying the delay time τ between the control and readout pulses as indicated in the inset of Fig. 7a. The observed decay of the excited qubit state is described by an exponential relaxation, giving $T_1 = 4.72 \pm 0.06 \,\mu\text{s}$, which compares favourably with the transmon relaxation times measured in earlier experiments [27,29–31], but which is a factor of 30 below the state of the art [32–34].

The qubit dephasing time was first measured using the Ramsey fringe visibility technique of two $\pi/2$ pulses separated by a variable delay τ , to include the influence of low-frequency noise that may adversely affect the photon source during operation. We found $T_{2,\mathrm{Ramsey}}=6.38~\mu\mathrm{s}$ presented in Fig. 7bi, by fitting a pair of sinusoids under an exponentially decaying envelope to the data recorded whilst the microwave excitation was detuned by $100\,\mathrm{kHz}$ from the qubit centre frequency. Fourier transforming the Ramsey fringe data (Fig. 7bii) reveals two oscillating components of equal magnitude, separated in frequency by $554\,\mathrm{kHz}$. We interpret these two components as arising from quasiparticle tunnelling events that take place on a characteristic timescale slow compared to each shot of the experiment, but fast compared to the 10^4-10^5 realisations that are averaged to provide the detected signal [32]. The visible beating in our device is due to our choice of a relatively large E_{C} in comparison with other qubits in the literature.

The echo technique was then used to eliminate this low-frequency noise, using a $(\pi/2) - \tau/2 - (\pi) - \tau/2 - (\pi/2)$ pulse sequence and recording the resonator dispersive shift to infer the qubit state. We found a value of $T_{2,\text{echo}} = 6.69 \pm 0.18 \,\mu\text{s}$ presented in Fig. 7c. Schematics of the pulse sequences used are shown in the insets of Fig. 7. The T_1 and $T_{2,\text{echo}}$ lifetimes of the qubit were then measured as a function of the qubit level spacing ν_{01} , which was swept by varying the magnetic field and hence E_J . At the $\Phi=0$ 'sweet spot' where the Josephson energy is first order insensitive to magnetic field, T_1 and T_2 take their maximum values. Once the qubit—resonator detuning Δ_0 begins to fall towards zero, the T_1 value is drastically reduced due to the Purcell effect [29], corresponding to relaxation of the qubit by microwave photon emission from the resonator. T_1 and $T_{2,\text{echo}}$ as a function of ν_{01} are plotted in Fig. 8.

6 Discussion

We now turn to the use of this device as a single microwave photon source. There are two different regimes in which a qubit coupled to a cavity can be used to generate



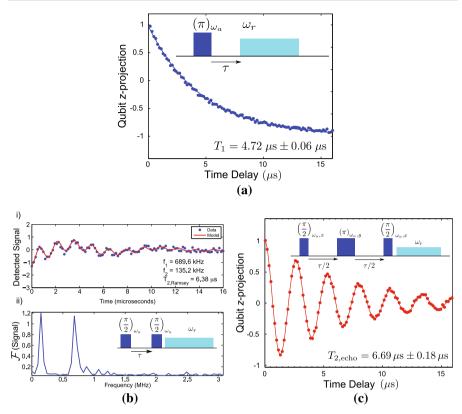


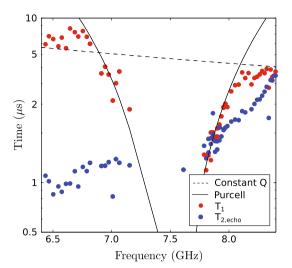
Fig. 7 The energy and phase relaxation times of the qubit measured at the 'sweet spot' $v_{01} \simeq 8.5$ GHz *Insets* show the pulse sequence used to record the relaxation rates. a Relaxation of the qubit. The fit to the data gives dephasing time $T_1 = 4.72 \pm 0.06 \, \mu \text{s}$. b (i.) Ramsey fringe measurement of the qubit reveals two oscillating components corresponding to the two different charge parity states of the qubit arising from quasiparticle tunnelling. (ii.) Fourier transform of the Ramsey fringes. The fit to the data gives $T_{2,\text{Ramsey}} = 6.38 \, \mu \text{s}$. c Coherent evolution of the qubit with the echo technique applied. The fit to the data gives dephasing time $T_{2,\text{echo}} = 6.69 \pm 0.18 \, \mu \text{s}$ (Color figure online)

single microwave photons: The qubit level spacing v_{01} can be static [10] or dynamically tuned to exchange photons with the resonator [11]. Whilst our device was designed for dynamic tuning, we will start by discussing the use of the simpler static case. Here the qubit–resonator detuning is fixed, the qubit is excited by a pulse from the flux tuning line, and the qubit emits a photon into the resonator which in turn releases the photon to the transmission line. The efficiency of such a source is given by the ratio of the excitation efficiency of the π -pulse used to excite the qubit, ϵ , times the emission rate of the excited qubit state from the resonator, $\gamma_{\kappa} = \kappa (g/2\pi \Delta_0)^2$ to the total decoherence rate of the system $T_1^{-1} + 2T_2^{-1}$ [10], such that

$$\eta_{\text{static}} = \epsilon \frac{f_0}{Q_c} \left(\frac{g}{2\pi \Delta_0} \right)^2 / \left(\frac{1}{T_1} + \frac{2}{T_2} \right),$$
(8)



Fig. 8 T_1 and $T_{2,echo}$ measured as a function of qubit transition frequency, showing an enhanced relaxation rate as the qubit transition frequency approaches that of the resonator. The solid *line* shows the predicted T_1 time if Purcell-driven relaxation were the only qubit relaxation mechanism using expressions from [29]; meanwhile, the dashed 'Constant O' line shows the relaxation rate predicted if the energy relaxation of the qubit scaled linearly with qubit level spacing. The observed data interpolate between these two limiting cases (Color figure online)



where the polarisation $0 \le \epsilon \le 1$ is estimated to $\epsilon \approx 1 - \tau_\pi/T_1 = 98.3\%$, where $\tau_\pi = 80$ ns is the duration of our π -pulse. For the parameters of our device, we obtain $\eta_{\rm static} = 0.9\%$ with the qubit at the sweet spot. Tuning the qubit towards the strong Purcell limit, we can approach $\eta_{\rm static} = 0.4\%$ based on the data in Fig. 8. To reach a much higher source efficiency with static qubit tuning, the resonator must be coupled strongly to the transmission line. The current coupling $Q_{\rm c} = 5500$ is instead close to the optimal value for a dynamic protocol to generate single photons with much higher efficiency.

The dynamic protocol calls for the qubit to first be excited by a π -pulse whilst detuned from the $\lambda/4$ resonator, followed by use of the flux tuning line to bring the qubit into resonance with the $\lambda/4$ structure for a duration 1/(2g) = 58 ns, effectively swapping the excitation from the qubit to the resonator. In our experiment, the flux tuning line used to modulate E_J has a bandwidth of 1 GHz, meaning that we can bring the qubit and resonator into resonance with one another in \sim 1 ns. The time taken to tune the qubit is therefore negligible compared to the π -pulse duration (80 ns) and vacuum Rabi swap (58 ns).

Once the excitation is transferred to the $\lambda/4$ resonator, the photon can either be absorbed by loss mechanisms in the resonator, or emitted into the feedline. The efficiency of the source under these operating conditions is therefore:

$$\eta_{\text{dynamic}} = \frac{Q_{\text{i}}}{Q_{\text{i}} + Q_{\text{c}}} \exp\left(-\frac{\tau_{\pi}}{T_{\text{l}}} - \frac{1}{2gT_{\text{l}}}\right),\tag{9}$$

where the first term accounts for photon absorption in the resonator and the exponential term for decays during the dynamic manipulation. The expression is valid in the fast driving and strong coupling limit where $gT_1 >> 1$ and $\Omega T_1 >> 1$, where g and Ω are the vacuum Rabi and driven Rabi angular frequencies, respectively. For our device, we find that $\eta_{\rm dynamic} \approx 85\%$.



The efficiency of the photon source when dynamic tuning is employed is limited principally by the loss mechanisms of the $\lambda/4$ resonator into which the photon is emitted. Our photon source efficiency could be improved by increasing Q_i . The best internal quality factor reported for 2D superconducting resonators at low excitation power is $Q_i \sim 2 \times 10^6$ [35].

The source efficiency can also be improved through lowering Q_c ; however Q_c cannot be lowered arbitrarily, as the Purcell effect will begin to shorten T_1 even when the resonator and qubit are detuned during the excitation phase of the dynamic protocol. There is then an optimal value of Q_c for a given qubit T_1 and resonator frequency $\omega_r/2\pi$. We find that the balance is achieved at:

$$Q_{\rm c}^{\rm optimal} = 2\pi\omega_r T_1 \left(\frac{g}{2\pi\Delta_0}\right)^2. \tag{10}$$

The best T_1 times reported in the literature for superconducting qubits are a factor of 15 higher than the device realised in this paper [36,37]. If we could build a device whose $T_1 \simeq 70~\mu s$, we would be able to decrease Q_c to 3500. If we were also able to make use of higher quality resonators, then we could hope to achieve a source efficiency $\eta_{\rm opt} > 99.5\%$. We note that through the use of Purcell filters [20], spontaneous emission from the qubit whilst the resonator and qubit are detuned can be suppressed, allowing room for further enhancement of source efficiency. We note also that other schemes exist for exciting the resonator using a detuned qubit, for instance, the parametric sideband modulation scheme [38], which can achieve driven qubit sideband-resonator Rabi frequencies that exceed the vacuum Rabi frequency of our device [39].

7 Conclusions

We have fabricated and characterised a superconducting qubit multiplexing circuit that appears to be promising for single microwave photon generation. We note that the resonators' frequencies and quality factors are close to the designed ones. The qubit parameters, such as the maximal energy gap, which exceeds the resonator frequency by about 1 GHz, are also close to the desired ones. Finally, the qubit—resonator and resonator-feedline couplings appeared to be consistent with expectations. The measured qubit coherence times and resonator intrinsic quality factors are consistent with those reported by other groups, but can be further improved to produce a single microwave photon source with an efficiency approaching 100%.

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Author contributions The device design was discussed by all authors. Iterations of device fabrication and measurement were performed by REG and SEdG using facilities at Lancaster University and Chalmers University of Technology, and by JS, REG, and OPS using facilities at Aalto University. REG, SEdG and YuAP wrote the paper with comments from all authors.



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